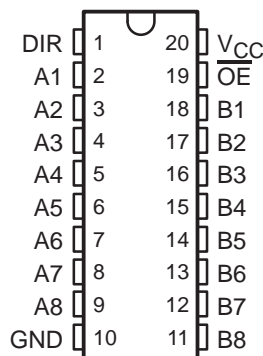


SN54LVCH245A, SN74LVCH245A OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

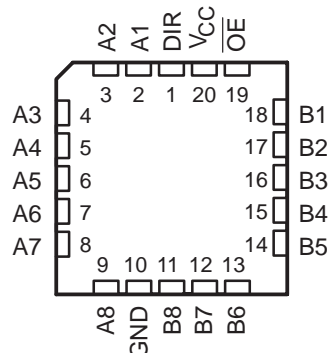
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- **EPIC™** (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- Power Off Disables Outputs, Permitting Live Insertion
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ($C = 200$ pF, $R = 0$)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Support Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Package, Ceramic Chip Carriers (FK), and DIPs (J)

SN54LVCH245A . . . J OR W PACKAGE
SN74LVCH245A . . . DB, DW, OR PW PACKAGE
(TOP VIEW)



SN54LVCH245A . . . FK PACKAGE
(TOP VIEW)



description

The SN54LVCH245A octal bus transceiver is designed for 2.7-V to 3.6-V V_{CC} operation and the SN74LVCH245A octal bus transceiver is designed for 1.65-V to 3.6-V V_{CC} operation.

These devices are designed for asynchronous communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN54LVCH245A is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74LVCH245A is characterized for operation from -40°C to 85°C .



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

SN54LVCH245A, SN74LVCH245A

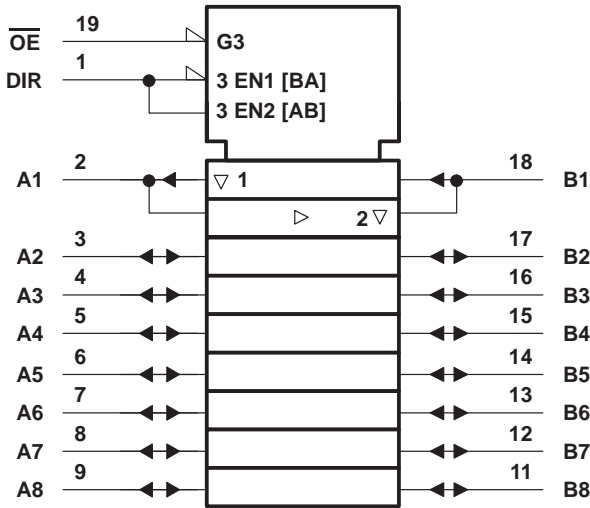
OCTAL BUS TRANSCEIVERS
WITH 3-STATE OUTPUTS

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FUNCTION TABLE

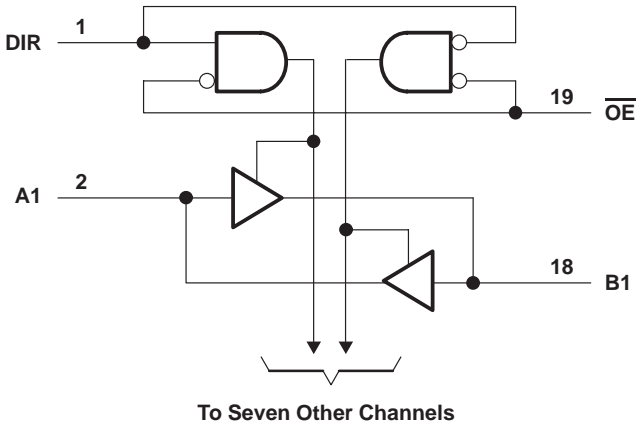
INPUTS		OPERATION
OE	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



SN54LVCH245A, SN74LVCH245A OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	–0.5 V to 6.5 V
Input voltage range, V_I : (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, V_O (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Continuous output current, I_O	±50 mA
Continuous current through V_{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DB package	115°C/W
DW package	97°C/W
PW package	128°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The value of V_{CC} is provided in the recommended operating conditions table.
3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

		SN54LVCH245A		SN74LVCH245A		UNIT
		MIN	MAX	MIN	MAX	
V_{CC} Supply voltage	Operating	2	3.6	1.65	3.6	V
	Data retention only	1.5		1.5		
V_{IH} High-level input voltage	$V_{CC} = 1.65$ V to 1.95 V			$0.65 \times V_{CC}$		V
	$V_{CC} = 2.3$ V to 2.7 V			1.7		
	$V_{CC} = 2.7$ V to 3.6 V	2		2		
V_{IL} Low-level input voltage	$V_{CC} = 1.65$ V to 1.95 V			$0.35 \times V_{CC}$		V
	$V_{CC} = 2.3$ V to 2.7 V			0.7		
	$V_{CC} = 2.7$ V to 3.6 V		0.8	0.8		
V_I Input voltage		0	5.5	0	5.5	V
V_O Output voltage	High or low state	0	V_{CC}	0	V_{CC}	V
	3 state	0	5.5	0	5.5	
I_{OH} High-level output current	$V_{CC} = 1.65$ V			–4		mA
	$V_{CC} = 2.3$ V			–8		
	$V_{CC} = 2.7$ V		–12	–12		
	$V_{CC} = 3$ V		–24	–24		
I_{OL} Low-level output current	$V_{CC} = 1.65$ V			4		mA
	$V_{CC} = 2.3$ V			8		
	$V_{CC} = 2.7$ V		12	12		
	$V_{CC} = 3$ V		24	24		
$\Delta t/\Delta v$ Input transition rise or fall rate		0	10	0	10	ns/V
T_A Operating free-air temperature		–55	125	–40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SN54LVCH245A, SN74LVCH245A

OCTAL BUS TRANSCEIVERS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	SN54LVCH245A			SN74LVCH245A			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V _{OH}		I _{OH} = −100 μA	1.65 V to 3.6 V				V _{CC} −0.2			V
			2.7 V to 3.6 V	V _{CC} −0.2						
		I _{OH} = −4 mA	1.65 V				1.2			
		I _{OH} = −8 mA	2.3 V				1.7			
		I _{OH} = −12 mA	2.7 V	2.2			2.2			
			3 V	2.4			2.4			
I _{OH} = −24 mA		3 V	2.2			2.2				
V _{OL}		I _{OL} = 100 μA	1.65 V to 3.6 V				0.2			V
			2.7 V to 3.6 V	0.2						
		I _{OL} = 4 mA	1.65 V				0.45			
		I _{OL} = 8 mA	2.3 V				0.7			
		I _{OL} = 12 mA	2.7 V	0.4			0.4			
		I _{OL} = 24 mA	3 V	0.55			0.55			
I _I	Control inputs	V _I = 0 to 5.5 V	3.6 V	±5			±5			μA
I _{off}		V _I or V _O = 5.5 V	0				±10			μA
I _I (hold)		V _I = 0.58 V	1.65 V				‡			μA
		V _I = 1.07 V					‡			
		V _I = 0.7 V	2.3 V				45			
		V _I = 1.7 V					−45			
		V _I = 0.8 V	3 V	75			75			
		V _I = 2 V		−75			−75			
		V _I = 0 to 3.6 V§		3.6 V	±500			±500		
I _{OZ} ¶		V _O = 0 to 5.5 V	3.6 V	±15			±10			μA
I _{CC}		V _I = V _{CC} or GND	3.6 V	10			10			μA
		3.6 V ≤ V _I ≤ 5.5 V#		10			10			
ΔI _{CC}		One input at V _{CC} − 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V	500			500			μA
C _i	Control inputs	V _I = V _{CC} or GND	3.3 V	4 12			4			pF
C _{io}	A or B ports	V _O = V _{CC} or GND	3.3 V	5.5 12			5.5			pF

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

‡ This information was not available at the time of publication.

§ This is the bus-hold maximum dynamic current required to switch the input from one state to another.

¶ For I/O ports, the parameter I_{OZ} includes the input leakage current.

This applies in the disabled state only.



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switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVCH245A				UNIT
			V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		
			MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A	8		1	7	ns
t _{en}	\overline{OE}	A or B	9.5		1	8.5	ns
t _{dis}	\overline{OE}	A or B	8.5		1	7.5	ns

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN74LVCH245A								UNIT
			V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A	†	†	†	†	7.3		1.5	6.3	ns
t _{en}	\overline{OE}	A or B	†	†	†	†	9.5		1.5	8.5	ns
t _{dis}	\overline{OE}	A or B	†	†	†	†	8.5		1.7	7.5	ns
t _{sk(o)} [†]									1		ns

† This information was not available at the time of publication.

‡ Skew between any two outputs of the same package switching in the same direction

operating characteristics, $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$	$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$	$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$	UNIT
				TYP	TYP	TYP	
C_{pd}	Power dissipation capacitance per transceiver	Outputs enabled	$f = 10\text{ MHz}$	†	†	47	pF
		Outputs disabled		†	†	2	

† This information was not available at the time of publication.

SN54LVCH245A, SN74LVCH245A

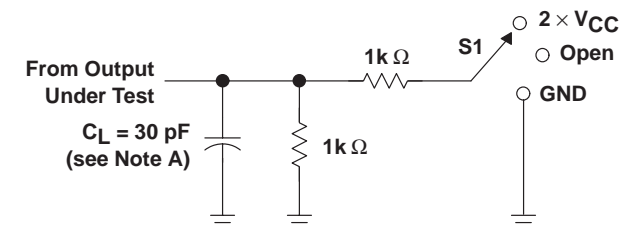
OCTAL BUS TRANSCEIVERS

WITH 3-STATE OUTPUTS

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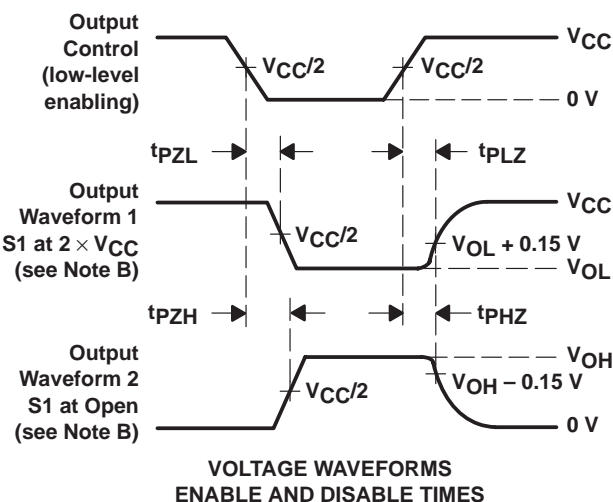
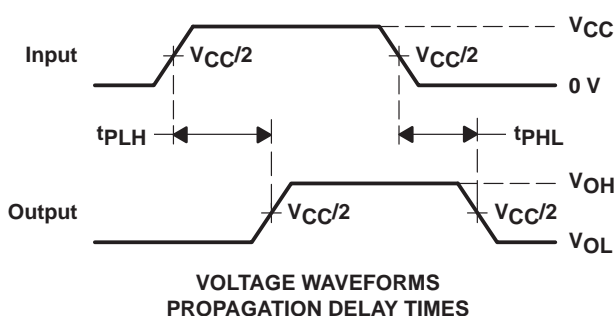
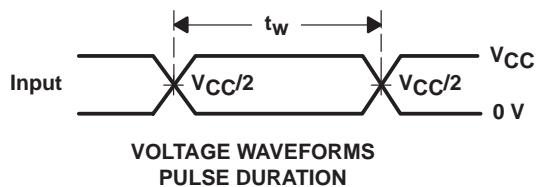
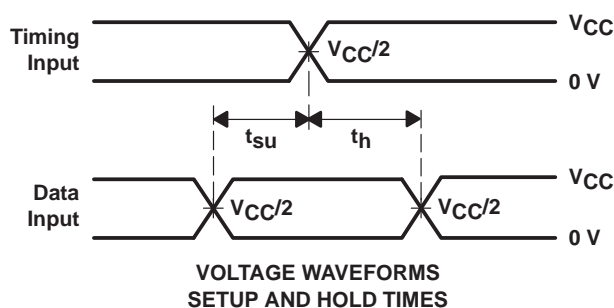
PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$$



LOAD CIRCUIT

TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$
t_{PHZ}/t_{PHL}	Open

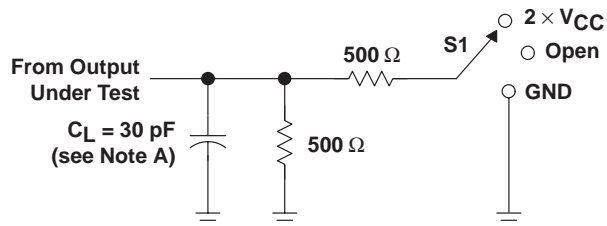


- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

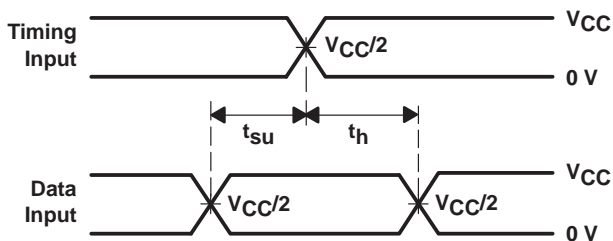
PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$$

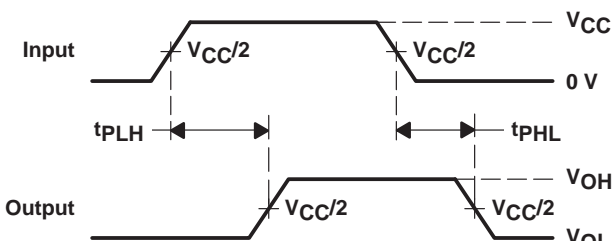


LOAD CIRCUIT

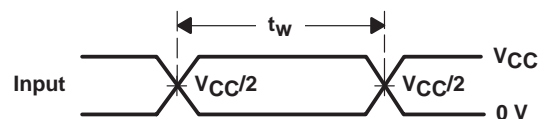
TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	2 $\times V_{CC}$
t_{PHZ}/t_{PZH}	GND



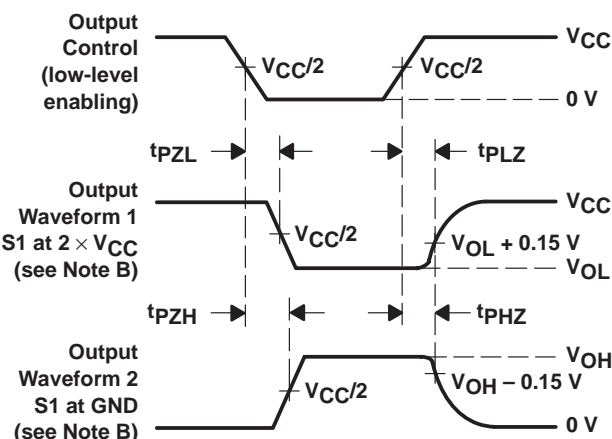
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

- NOTES: A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$.
- D. The outputs are measured one at a time with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 2. Load Circuit and Voltage Waveforms

SN54LVCH245A, SN74LVCH245A

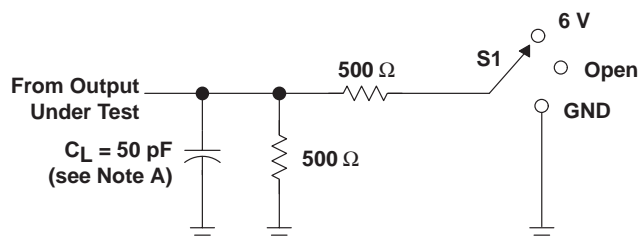
OCTAL BUS TRANSCEIVERS

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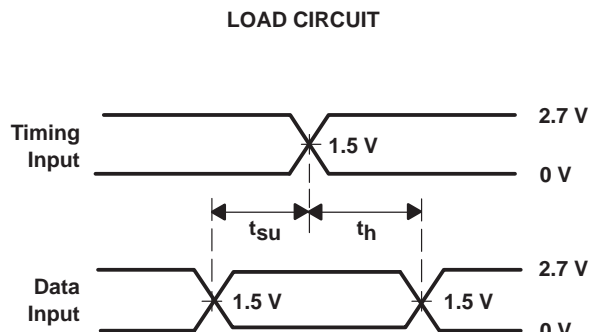
PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7\text{ V AND } 3.3\text{ V} \pm 0.3\text{ V}$

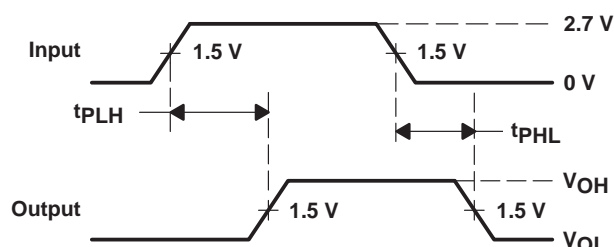


LOAD CIRCUIT

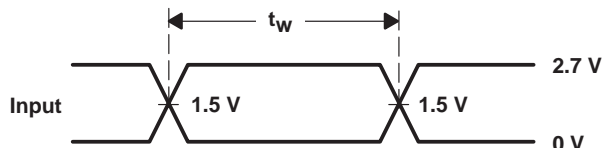
TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



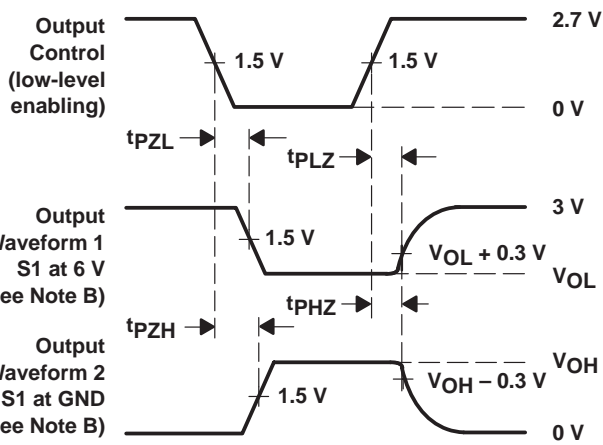
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

- NOTES:
- C_L includes probe and jig capacitance.
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 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\text{ }\Omega$, $t_r \leq 2.5\text{ ns}$, $t_f \leq 2.5\text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms

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